

MatchBox² series



ADVANTAGES:

One size
Self-contained design
Compact and efficient
Variety of wavelengths
Dedicated for OEM integration

APPLICATIONS:

Raman spectroscopy
Fluorescence imaging
Flow cytometry
Holography
Metrology
Optical guiding

1342 nm

1319 nm

1122 nm

1064 nm

1030 nm

980 nm

975 nm

946 nm

914 nm

850 nm

830 nm

808 nm

785 nm

671 nm

660 nm

635 nm

633 nm

593 nm

589 nm

561 nm

532 nm

515 nm

500 nm

491 nm

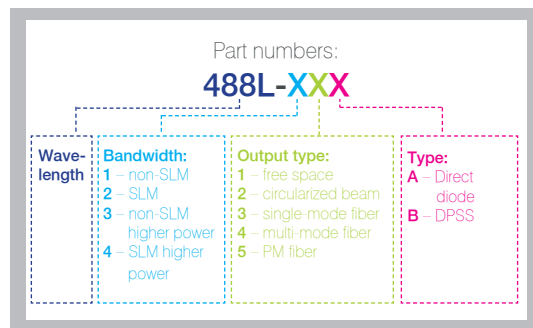
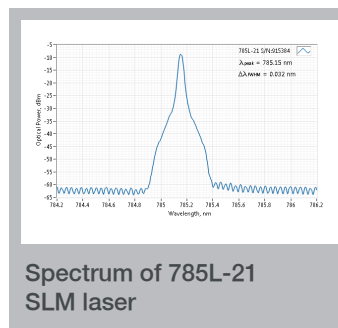
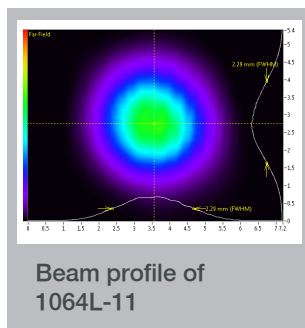
488 nm

473 nm

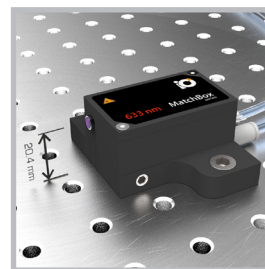
457 nm

445 nm

405 nm



Standard accessories:



www.integratedoptics.com
Made in Lithuania (EU)

MatchBox™ is an unregistered trademark of Integrated Optics, UAB
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Wave-length (nm)	Narrow linewidth	Type	Optical power (free space)	Wave-length tolerance	Spectral linewidth (typical)	Power stability (RMS, 8 hrs)	Noise 1 min. (20 Hz – 100 kHz)	Output power (SM PM fiber)	Output power (MM fiber)
405	Yes	VBG Diode	30 mW	+ 0.3 nm	<3 pm	1%	0.2%	10 mW	20 mW
	No	Diode	130 mW	+/- 3 nm	1 nm	1%	0.2%	40 mW	90 mW
445	No	Diode	50 mW	+/- 3 nm	1 nm	1%	0.2%	15 mW	35 mW
488	Yes	VBG Diode	30 mW	+ 0.2 nm	<3 pm	1%	0.2%	10 mW	15 mW
	No	Diode	45 mW	+/- 3 nm	1 nm	1%	0.2%	20 mW	30 mW
515	No	Diode	40 mW	+/- 5 nm	1 nm	1%	0.2%	20 mW	30 mW
532	Yes	DPSS	50 mW	+ 0.3 nm	0.2 pm	1%	0.2%	25 mW	40 mW
	No	DPSS	200 mW	+/- 0.1 nm	0.3 nm	1%	N/A	100 mW	160 mW
	No	DPSS	500 mW	+/- 0.1 nm	0.3 nm	1%	N/A	N/A	350 mW
632.8	Yes	VBG Diode	60 mW	+/- 0.1 nm	<2 pm	1%	0.2%	30 mW	40 mW
635	Yes	VBG Diode	90 mW	+/- 0.1 nm	<2 pm	1%	0.2%	45 mW	65 mW
	No	Diode	150 mW	+/- 3 nm	1 nm	1%	0.2%	75 mW	120 mW
660	No	Diode	110 mW	+/- 3 nm	1 nm	1%	0.2%	45 mW	90 mW
783	Yes	VBG Diode	90 mW	+ 0.1 nm	<2 pm	1%	0.2%	45 mW	60 mW
785	Yes	VBG Diode	100 mW	+ 0.1 nm	<2 pm	1%	0.2%	50 mW	70 mW
	Yes	VBG Diode	500 mW	+ 0.5 nm	75 pm	1%	0.2%	N/A	350 mW
	No	Diode	150 mW	+/- 3 nm	1 nm	1%	0.2%	60 mW	120 mW
808	Yes	VBG Diode	100 mW	+ 0.2 nm	<2 pm	1%	0.2%	40 mW	80 mW
	No	Diode	120 mW	+/- 3 nm	1 nm	1%	0.2%	50 mW	85 mW
830	No	Diode	130 mW	+/- 10 nm	1 nm	1%	0.2%	50 mW	90 mW
915	No	Diode	200 mW	+/- 3 nm	1 nm	1%	0.2%	80 mW	140 mW
975	No	Diode	200 mW	+/- 3 nm	1 nm	1%	0.2%	80 mW	120 mW
980	No	Diode	200 mW	+/- 3 nm	1 nm	1%	0.2%	80 mW	120 mW
1029	Yes	DPSS	400 mW	+/- 0.25 nm	<75 pm	1%	0.2%	200 mW	280 mW
1030	No	DPSS	500 mW	+/- 3 nm	2 nm	1%	N/A	300 mW	400 mW
1064	Yes	DPSS	400 mW	+ 0.3 nm	<0.2 pm	1%	0.2%	200 mW	280 mW
	No	DPSS	500 mW	+/- 0.1 nm	0.5 nm	1%	N/A	300 mW	400 mW

Other wavelengths on request: 457 nm, 473 nm, 491 nm, 500 nm, 561 nm, 589 nm, 593 nm, 671 nm, 850 nm, 946 nm, 1123 nm, 1319 nm, 1342 nm.

OTHER PARAMETERS:

- Transversal mode: TEM00, except 500 mW 532 nm and 785 nm
- Beam diameter at aperture (1/e²): <2 mm
- Beam divergence (full angle): <2 mrad
- Beam quality, M2: <1.3, except 500 mW 532 nm and 785 nm
- Power stability of fiber-coupled lasers is <2 % RMS over 8 hrs
- SLM fiber coupled lasers are made with FC/APC connectors
- Non-SLM lasers are made with FC/PC connectors
- Standard length of a fiber is 1 m
- Control interface type: UART, USB
- Operation mode: continuous wave (CW)
- External power supply requirement: +5 VDC, 5 A for DPSS, 1.5 A for diode
- Dimensions (L-W-H): 50 x 30 x 16 mm (excluding pins)
- Beam height from the base: 8.4 mm (+/- 0.3 mm)
- Beam pointing angle tolerance: +/-2 mrad (vertical), +/-3 mrad (horizontal)
- Heatsink requirement: diode <1 °C/W, DPSS <0.5 °C/W
- Optimum heatsink temperature (non-condensing):
 - Diode lasers - +15...+30 °C
 - Max. heatsink temperature 35 °C
- Internal temperature stabilization : TEC
- Overheat protection: Yes
- Storing temperature (non-condensing): -10 to +50 °C
- Warranty: 12 months, Hours limitation of 5000 hrs apply for 405, 445, 488, 515, 633, 635, 660 nm diode lasers

Custom wavelengths and specifications are available on request